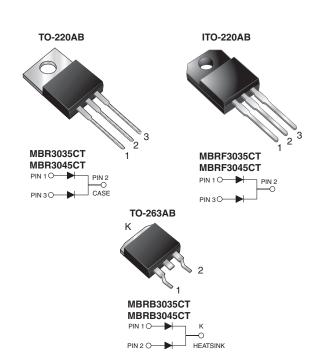


Vishay General Semiconductor

## **Dual Common Cathode Schottky Rectifier**



| PRIMARY CHARACTERISTICS |            |  |  |  |  |
|-------------------------|------------|--|--|--|--|
| I <sub>F(AV)</sub>      | 15 A x 2   |  |  |  |  |
| V <sub>RRM</sub>        | 35 V, 45 V |  |  |  |  |
| I <sub>FSM</sub>        | 200 A      |  |  |  |  |
| V <sub>F</sub>          | 0.60 V     |  |  |  |  |
| T <sub>J</sub> max.     | 150 °C     |  |  |  |  |

#### **FEATURES**

- Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- · High forward surge capability
- High frequency operation
- · Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- · Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

#### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| <b>MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C unless otherwise PARAMETER                    |              | SYMBOL             | MBR3035CT     | MBR3045CT | UNIT |  |
|--|--------------|--------------------|---------------|-----------|------|--|
| Maximum repetitive peak reverse voltage  |              | $V_{RRM}$          | 35            | 45        |      |  |
| Working peak reverse voltage   |              | V <sub>RWM</sub>   | 35            | 45        | V    |  |
| Maximum DC blocking voltage  |              | V <sub>DC</sub>    | 35            | 45        |      |  |
| Maximum average forward rectified current  | total device | 1                  | 30            |           |      |  |
|  | per diode    | I <sub>F(AV)</sub> | 15            |           |      |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode |              | I <sub>FSM</sub>   | 200           |           | А    |  |
| Peak repetitive reverse current per diode at t <sub>p</sub> = 2.0 μs, 1 kHz                  |              | I <sub>RRM</sub>   | 2.0           |           |      |  |
| Voltage rate of change (rated V <sub>R</sub> )   |              | dV/dt              | 10 000        |           | V/µs |  |
| Operating junction temperature range   |              | $T_J$              | - 65 to + 150 |           | °C   |  |
| Storage temperature range  |              | T <sub>STG</sub>   | - 65 to + 175 |           |      |  |
| Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min                       |              | V <sub>AC</sub>    | 1500          |           | V    |  |



# MBR(F,B)3035CT, MBR(F,B)3045CT

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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted) |                               |                       |                         |       |      |  |
|---|-------------------------------|-----------------------|-------------------------|-------|------|--|
| PARAMETER   | SYMBOL                        | TEST CONDITIONS       |                         | VALUE | UNIT |  |
|   |                               | I <sub>F</sub> = 20 A | T <sub>C</sub> = 125°C  | 0.60  |      |  |
| Maximum instantaneous forward voltage per diode                                   | V <sub>F</sub> <sup>(1)</sup> | I <sub>F</sub> = 30 A | $T_C = 25^{\circ}C$     | 0.76  | V    |  |
|   |                               | I <sub>F</sub> = 30 A | T <sub>C</sub> = 125°C  | 0.72  |      |  |
| Maximum instantaneous reverse current at DC blocking voltage per diode            | I <sub>R</sub> <sup>(1)</sup> | Rated V <sub>R</sub>  | T <sub>J</sub> = 25 °C  | 1.0   | - mA |  |
|   |                               |                       | T <sub>J</sub> = 125 °C | 60    |      |  |

#### **Notes**

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms

| THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted) |                |     |      |      |      |
|---|----------------|-----|------|------|------|
| PARAMETER   | SYMBOL         | MBR | MBRF | MBRB | UNIT |
| Typical thermal resistance per diode                                    | $R_{	heta JC}$ | 1.5 | 4.5  | 1.5  | °C/W |

| ORDERING INFORMATION (Example) |                      |                 |              |               |               |  |  |
|--------------------------------|----------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE                        | PREFERRED P/N        | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |  |
| TO-220AB                       | MBR3045CT-E3/45      | 1.85            | 45           | 50/tube       | Tube          |  |  |
| ITO-220AB                      | MBRF3045CT-E3/45     | 1.99            | 45           | 50/tube       | Tube          |  |  |
| TO-263AB                       | MBRB3045CT-E3/45     | 1.35            | 45           | 50/tube       | Tube          |  |  |
| TO-263AB                       | MBRB3045CT-E3/81     | 1.35            | 81           | 800/reel      | Tape and reel |  |  |
| TO-220AB                       | MBR3045CTHE3/45 (1)  | 1.85            | 45           | 50/tube       | Tube          |  |  |
| ITO-220AB                      | MBRF3045CTHE3/45 1)  | 1.99            | 45           | 50/tube       | Tube          |  |  |
| TO-263AB                       | MBRB3045CTHE3/45 (1) | 1.35            | 45           | 50/tube       | Tube          |  |  |
| TO-263AB                       | MBRB3045CTHE3/81 (1) | 1.35            | 81           | 800/reel      | Tape and reel |  |  |

### Note

(1) AEC-Q101 qualified

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### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

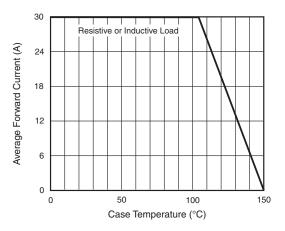


Fig. 1 - Forward Current Derating Curve

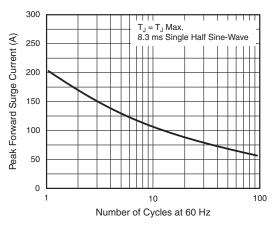


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

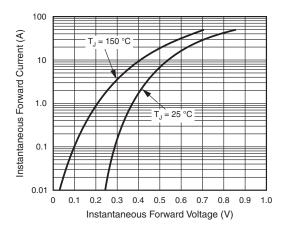


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

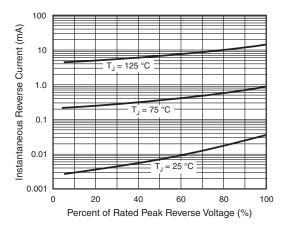


Fig. 4 - Typical Reverse Characteristics Per Diode

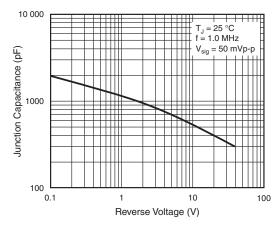


Fig. 5 - Typical Junction Capacitance Per Diode

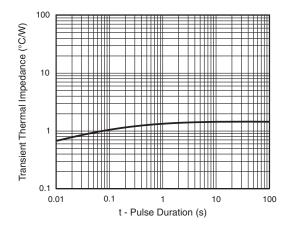


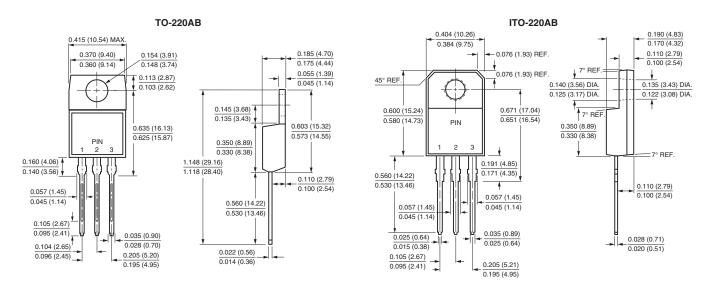
Fig. 6 - Typical Transient Thermal Impedance Per Diode



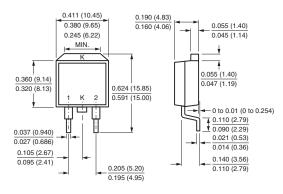
## MBR(F,B)3035CT, MBR(F,B)3045CT

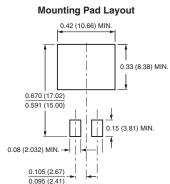
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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



#### TO-263AB







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